# **Trench Power MOSFET**

12 V, 3.3 A, Single P–Channel, ESD Protected SC–88

### Features

- Leading Trench Technology for Low RDS(ON) Extending Battery Life
- SC-88 Small Outline (2x2 mm, SC70-6 Equivalent)
- Gate Diodes for ESD Protection
- Pb-Free Packages are Available

#### Applications

- High Side Load Switch
- Cell Phones, Computing, Digital Cameras, MP3s and PDAs

Param	Symbol	Value	Units			
Drain-to-Source Voltage	V <sub>DSS</sub>	-12	V			
Gate-to-Source Voltage	V <sub>GS</sub>	±12	V			
Continuous Drain	Steady	T <sub>A</sub> = 25 °C	۱ <sub>D</sub>	-2.7	А	
Current (Note 1)	State	T <sub>A</sub> = 85 °C		-2.0		
	t ≤ 5 s	T <sub>A</sub> = 25 °C		-3.3		
Power Dissipation (Note 1)	Steady State	T <sub>A</sub> = 25 °C	P <sub>D</sub>	0.625	W	
Pulsed Drain Current	I <sub>DM</sub>	-8.0	А			
Operating Junction and S	T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C			
Source Current (Body Diode)			۱ <sub>S</sub>	-0.8	А	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise stated)



Parameter	Symbol	Мах	Units
Junction-to-Ambient - Steady State	$R_{\theta JA}$	200	°C/W
Junction-to-Ambient – t $\leq$ 5 s	$R_{\theta JA}$	141	
Junction-to-Lead - Steady State	$R_{\theta JL}$	102	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).

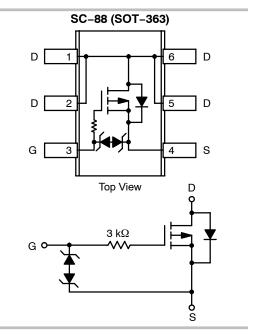
 $(\bigcirc u \text{ area} = 1.127 \text{ in sq} [1 \text{ oz}] \text{ including traces}).$ 



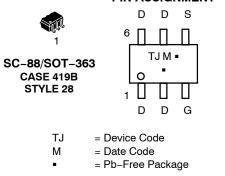
## **ON Semiconductor®**

## http://onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> Typ	I <sub>D</sub> Max
	45 mΩ @ –4.5 V	
-12 V	67 mΩ @ –2.5 V	-3.3 A
	133 mΩ @ −1.8 V	



MARKING DIAGRAM & PIN ASSIGNMENT



(Note: Microdot may be in either location)

## ORDERING INFORMATION

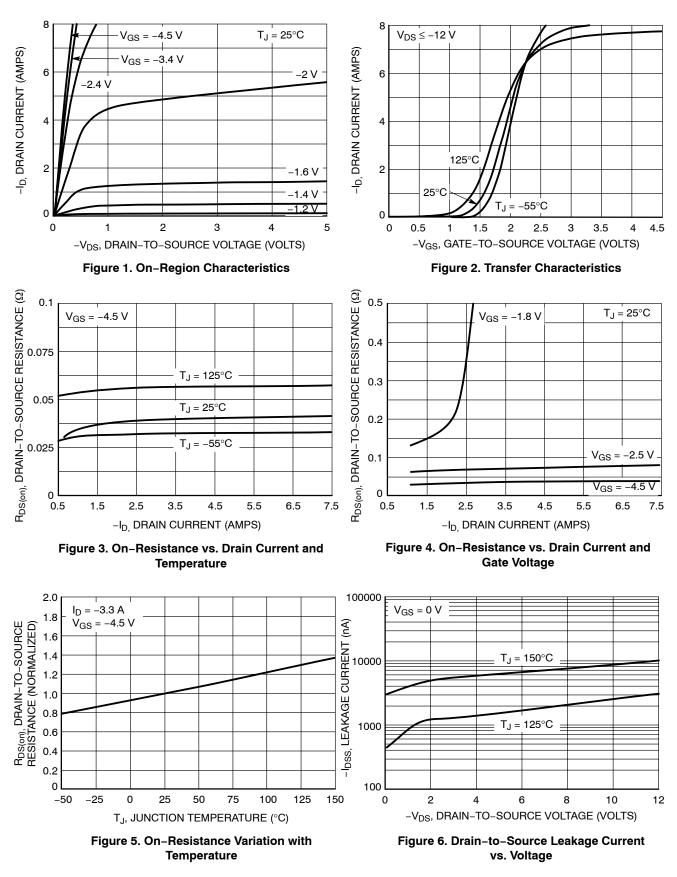
See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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## ELECTRICAL CHARACTERISTICS (TJ=25°C unless otherwise stated)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, I <sub>D</sub> = -250 $\mu$ A		-12			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				10		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = -9.6 V,$ $V_{DS} = 0 V$	$T_J = 25^{\circ}C$			-1.0	μΑ
			T <sub>J</sub> = 125°C		-2.5		
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$I_{GSS} = V_{DS} = 0 V, V_{GS} = \pm 4.5 V$ $V_{DS} = 0 V, V_{GS} = \pm 12 V$				±1.5	μΑ
						±10	mA
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS}$ = $V_{DS}$ , $I_D$ = 100 $\mu$ A		-0.40			V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				3.4		mV/°C
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	$V_{GS}$ = -4.5 V, I <sub>D</sub> = -3.3 A			45	60	mΩ
	V <sub>GS</sub> = -2.5	V <sub>GS</sub> = -2.5 V,	<sub>D</sub> = –2.9 A		67	90	1
V <sub>GS</sub> =		V <sub>GS</sub> = -1.8 V,	V, I <sub>D</sub> = -1.0 A 13		133	160	
Forward Transconductance	9FS	$V_{GS}$ = -10 V, I <sub>D</sub> = -3.3 A			15		S
CHARGES AND CAPACITANCES							
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = -12 V			850		pF
Output Capacitance	C <sub>OSS</sub>				170		
Reverse Transfer Capacitance	C <sub>RSS</sub>				110		
Total Gate Charge	Q <sub>G(TOT)</sub>	V <sub>GS</sub> = -4.5 V, V <sub>DS</sub> = -5.0 V, I <sub>D</sub> = -3.3 A			8.6		nC
Gate-to-Source Charge	Q <sub>GS</sub>				1.3		1
Gate-to-Drain Charge	Q <sub>GD</sub>				2.2		7
Gate Resistance	R <sub>G</sub>				3000		Ω
SWITCHING CHARACTERISTICS (No	te 3)						
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{GS}$ = -4.5 V, $V_{DD}$ = -6.0 V, I <sub>D</sub> = -1.0 A, R <sub>G</sub> = 6.0 $\Omega$			0.86		μs
Rise Time	t <sub>r</sub>				1.5		
Turn-Off Delay Time	t <sub>d(OFF)</sub>				3.5		
Fall Time	t <sub>f</sub>				3.9		<u> </u>
DRAIN-SOURCE DIODE CHARACTE	RISTICS (Note :	2)					
Forward Diode Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V,	$T_J = 25^{\circ}C$		-0.85	-1.2	V
	I <sub>S</sub> = -3.3 Å		T <sub>J</sub> = 125°C		-0.7		

Pulse Test: pulse width ≤ 300μs, duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.



#### TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = 25°C unless otherwise noted)

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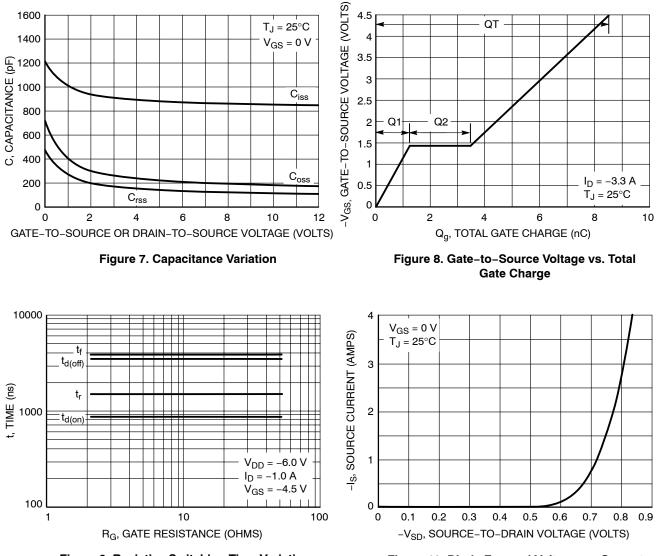


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

Figure 10. Diode Forward Voltage vs. Current

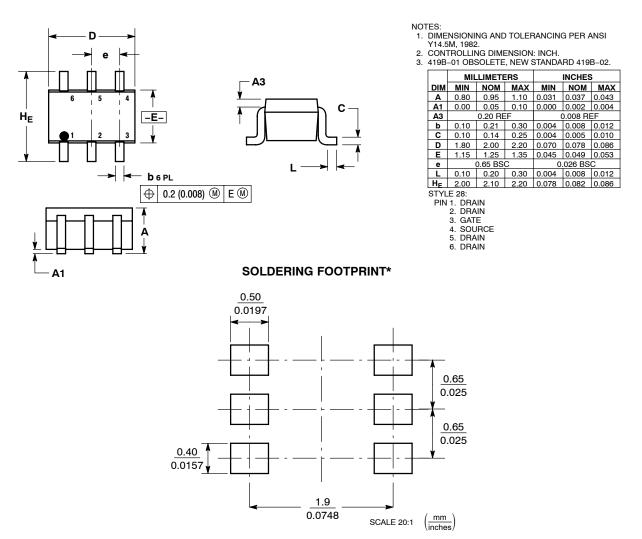
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTJS3151PT1	SC-88	3000 Tape & Reel
NTJS3151PT1G	SC–88 (Pb–Free)	3000 Tape & Reel
NTJS3151PT2	SC-88	3000 Tape & Reel
NTJS3151PT2G	SC-88 (Pb-Free)	3000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE W



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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